November 2013



# FGPF4633 330 V PDP Trench IGBT

## Features

- High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> = 1.55 V @ I<sub>C</sub> = 70 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

## Applications

• PDP TV, Consumer Appliances, Lighting

## **General Description**

Using novel trench IGBT technology, Fairchild's new series of trench IGBTs offer the optimum performance for consumer appliances, PDP TV and lighting applications where low conduction and switching losses are essential.



## **Absolute Maximum Ratings**

Symbol	Description	Ratings	Unit	
V <sub>CES</sub>	Collector to Emitter Voltage	330	V	
V <sub>GES</sub>	Gate to Emitter Voltage	± 30	V	
I <sub>C pulse(1)*</sub>	Collector Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	300	A
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	30.5	W
	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	12.2	W
TJ	Operating Junction Temperature	-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second	300	°C	

## **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	4.1	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

Notes:

(1) Half Sine Wave, D < 0.01, pluse width < 5  $\mu sec$ 

\* Ic\_pluse limited by max Tj

Part Nun	nber Top N	lark	Package	Packing Method Tube	Reel Size	Та	Tape Width       N/A		Quantity 50	
FGPF46	33 FGPF4	FGPF4633	TO-220F		N/A					
Electric	al Characte	eristi	cs of the l	<b>GBT</b> $T_{C} = 25^{\circ}C$ unless other	nerwise noted					
Symbol			Test Conditions		Min.	Тур.	Max.	Unit		
Off Charac	toristics									
BV <sub>CES</sub>	Collector to Emit	ter Brea	akdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA		330	-	-	V	
∆BV <sub>CES</sub>			, in the second se			000				
$\Delta T_J$	Voltage	perature Coefficient of Breakdown age		$V_{GE}$ = 0 V, $I_C$ = 250 $\mu$ A		-	0.3	-	V/ºC	
I <sub>CES</sub>	Collector Cut-Of	ector Cut-Off Current		$V_{CE} = V_{CES}, V_{GE} = 0 V$		-	-	100	μA	
I <sub>GES</sub>	G-E Leakage Cu	urrent		$V_{GE} = V_{GES}, V_{CE} = 0$ V	/	-	-	±400	nA	
On Charact	teristics									
V <sub>GE(th)</sub>	G-E Threshold \	/oltage		I <sub>C</sub> = 250 μA, V <sub>CE</sub> = V <sub>G</sub>	F	2.4	3.3	4.0	V	
V <sub>CE(sat)</sub> Collect				I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V		-	1.1	-	V	
	Collector to Emi	ollector to Emitter aturation Voltage		I <sub>C</sub> = 40 A, V <sub>GE</sub> = 15 V		-	1.35	-		
				$I_{C} = 70 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 25^{\circ}\text{C}$		-	1.55	1.8	V	
				$I_{C} = 70 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$		-	1.61	-	V	
Dvnamic C	haracteristics				I					
C <sub>ies</sub>	Input Capacitan	ce				-	1715	-	pF	
C <sub>oes</sub>		Dutput Capacitance		$V_{CE} = 30 V, V_{GE} = 0 V,$		-	75	-	pF	
C <sub>res</sub>	Reverse Transfe	er Capa	citance	f = 1 MHz		-	55	-	pF	
Switching	Characteristics			1	I					
t <sub>d(on)</sub>	Turn-On Delay 1	Time				-	8	- /	ns	
t <sub>r</sub>	Rise Time	e Time m-Off Delay Time		$V_{CC} = 200 \text{ V}, I_C = 20 \text{ A}$	. –	-	30	-	ns	
t <sub>d(off)</sub>	Turn-Off Delay T			$R_G = 5 \Omega$ , $V_{GE} = 15 V$ Resistive Load, $T_C = 2$	5°C	-	52	7.	ns	
t <sub>f</sub>	Fall Time					-	260	-	ns	
t <sub>d(on)</sub>	Turn-On Delay 1	ırn-On Delay Time se Time ırn-Off Delay Time		$V_{CC} = 200 \text{ V}, \text{ I}_{C} = 20 \text{ A},$ $R_{G} = 5 \Omega, \text{ V}_{GE} = 15 \text{ V},$ Resistive Load, $T_{C} = 125^{\circ}\text{C}$		-	8	•	ns	
t <sub>r</sub>	Rise Time				ι,	-	32	-	ns	
t <sub>d(off)</sub>	Turn-Off Delay T				25°C	-	53	-	ns	
t <sub>f</sub>	Fall Time			3		-	341	-	ns	
Qg	Total Gate Charg	Total Gate Charge		\/ _ 200 \/   _ 20 A		-	60	-	nC	
Q <sub>ge</sub>	Gate to Emitter	Charge		V <sub>CE</sub> = 200 V, I <sub>C</sub> = 20 A V <sub>GE</sub> = 15 V		-	8	-	nC	
Q <sub>gc</sub>	Gate to Collecto	ate to Collector Charge				-	20	-	nC	

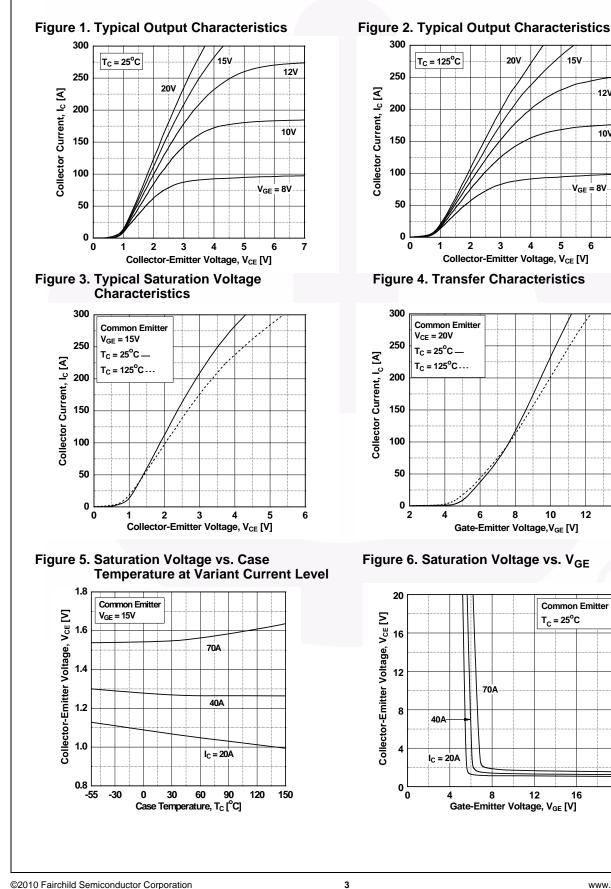
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12V

10V

7

14



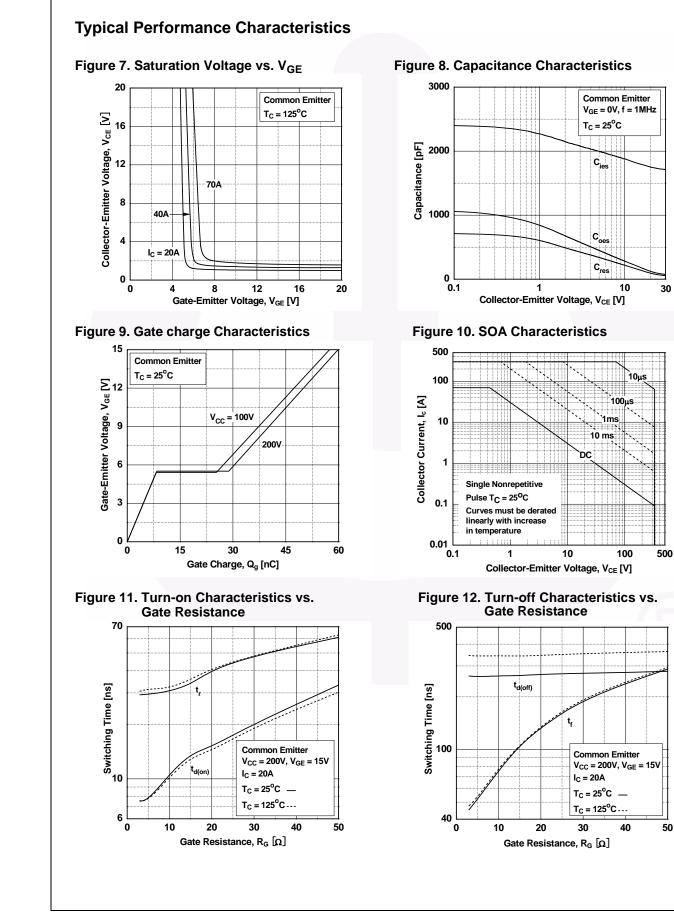
**Typical Performance Characteristics** 

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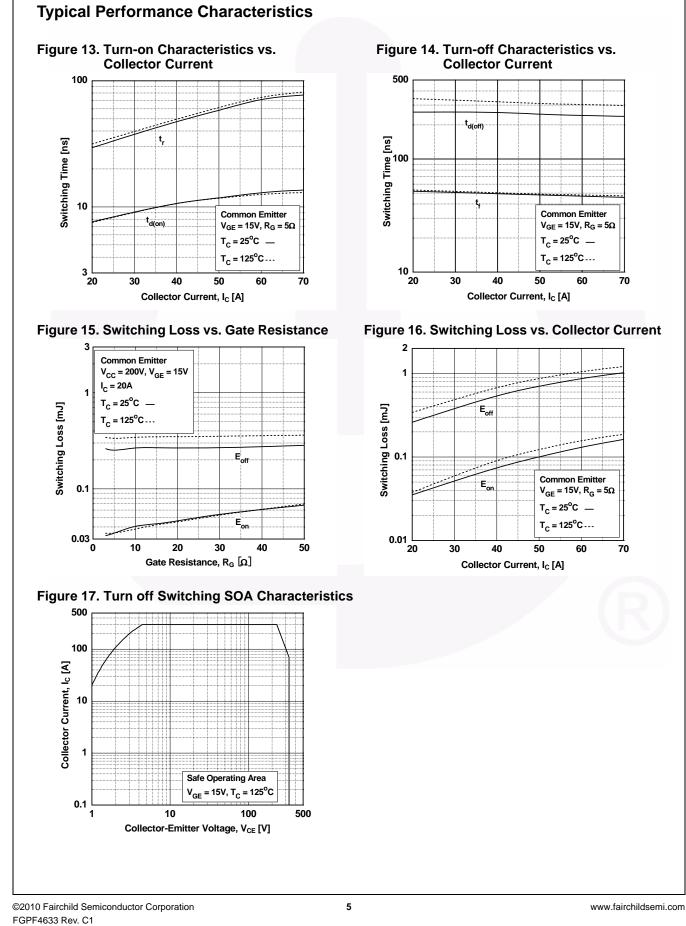
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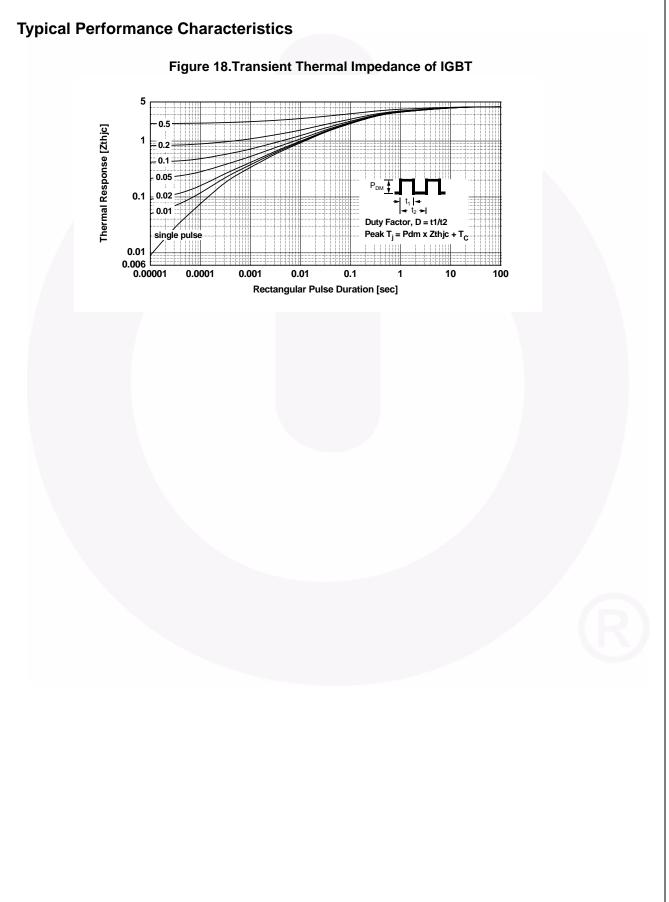
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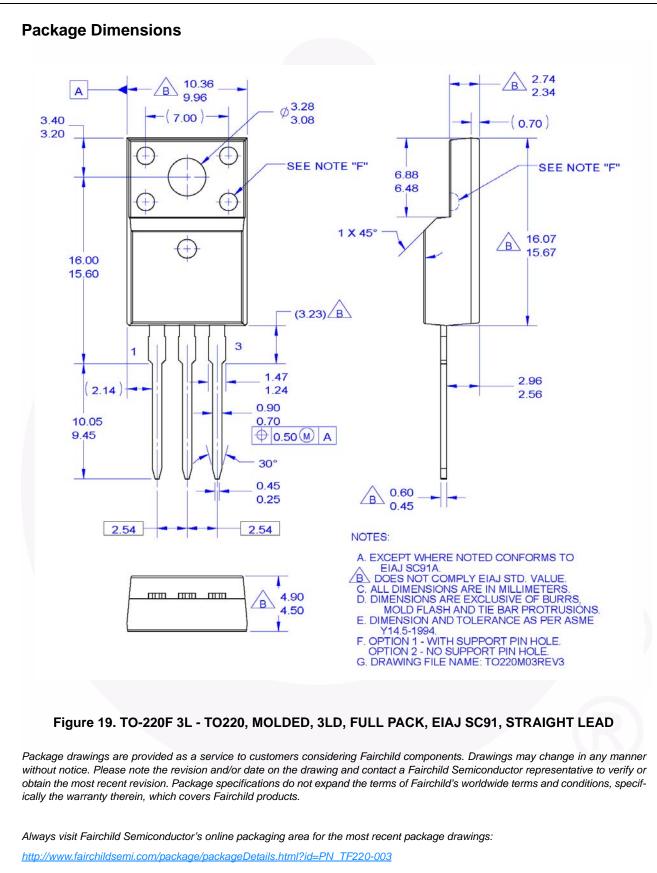


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